# NSN 5962-01-236-6875

Memory Microcircuit - Page 1 of 1



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## **Body Length:**

Between 1.230 inches and 1.290 inches

## Body Width:

Between 0.510 inches and 0.540 inches

## **Body Height:**

0.180 inches

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **Features Provided:**

Hermetically sealed and bipolar and schottky and programmable

#### **Inclosure Material:**

Ceramic and glass

#### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

14 input

Terminal Surface Treatment:

Solder

## Voltage Rating And Type Per Characteristic:

5.0 volts power source

## **Time Rating Per Chacteristic:**

65.00 nanoseconds propagation delay time, low to high level output and 65.00 nanoseconds propagation delay time, high to low level output

## Memory Device Type:

Rom

# Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# Terminal Type And Quantity:

24 printed circuit

# Shelf Life:

N/a

# Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

#### Fiig:

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